



UTR2101

LINEAR INTEGRATED CIRCUIT

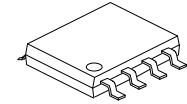
HALF-BRIDGE DRIVER

DESCRIPTION

The **UTR2101** is a high voltage, high speed power MOSFET and IGBT driver with independent high-side and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600V.

FEATURES

- * Floating channel designed for bootstrap operation
- * Fully operational to +600V
- * Tolerant to negative transient voltage, dV/dt immune
- * Gate drive supply range from 10V to 20V
- * Undervoltage lockout
- * 3.3V, 5V, and 15V input logic compatible
- * Matched propagation delay for both channels
- * Outputs in phase with inputs



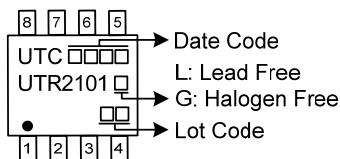
SOP-8

ORDERING INFORMATION

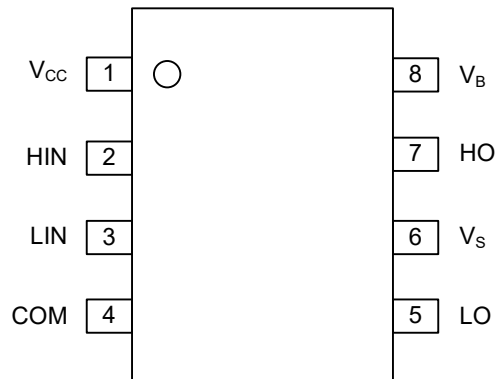
Ordering Number		Package	Packing
Lead Free	Halogen Free		
UTR2101L-S08-R	UTR2101G-S08-R	SOP-8	Tape Reel

UTR2101G-S08-R	(1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) S08: SOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING



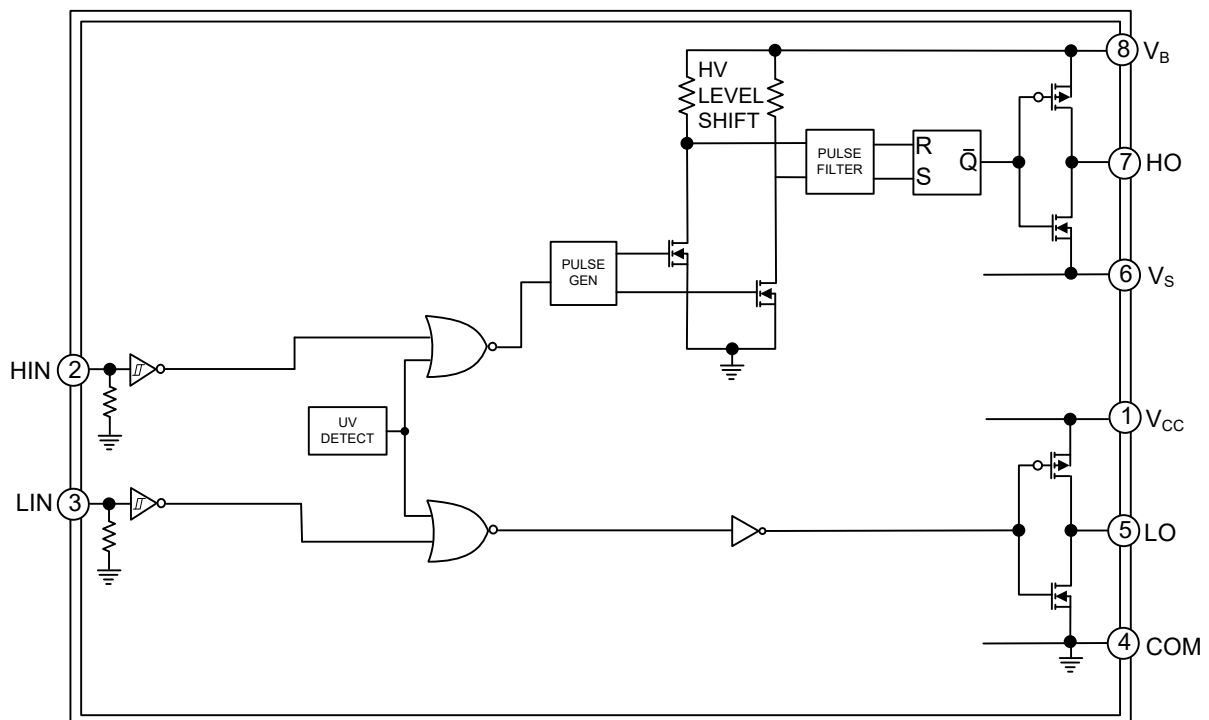
PIN CONFIGURATION



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	V_{CC}	Low-side and logic fixed supply
2	HIN	Logic input for high-side gate driver output (HO), in phase
3	LIN	Logic input for low-side gate driver output (LO), out of phase
4	COM	Low-side return
5	LO	Low-side gate drive output
6	V_S	High-side floating supply return
7	HO	High-side gate drive output
8	V_B	High-side floating supply

BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
High-Side Floating Absolute Voltage	V _B	625	V
High-Side Floating Supply Offset Voltage	V _S	V _B -25 ~ V _B +0.3	V
High-Side Floating Output Voltage	V _{HO}	V _S -0.3 ~ V _B +0.3	V
Low-Side and logic Fixed Supply Voltage	V _{CC}	-0.3 ~ 25	V
Low-Side Output Voltage	V _{LO}	-0.3 ~ V _{CC} +0.3	V
Logic Input Voltage (HIN & LIN)	V _{IN}	-0.3 ~ V _{CC} +0.3	V
Power Dissipation	P _D	0.625	W
Maximum Junction Temperature	T _J	+150	°C
Maximum Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 2. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

■ RECOMMENDED OPERATING RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
High-Side Floating Absolute Voltage	V _B	V _S +10 ~ V _S +20	V
High-Side Floating Supply Offset Voltage	V _S	600 (Note)	V
High-Side Floating Output Voltage	V _{HO}	V _S ~ V _B	V
Low-Side and logic Fixed Supply Voltage	V _{CC}	10 ~ 20	V
Low-Side Output Voltage	V _{LO}	0 ~ V _{CC}	V
Logic Input Voltage (HIN & LIN)	V _{IN}	0 ~ V _{CC}	V
Ambient Temperature	T _A	-40 ~ +125	°C

Note: Logic operational for V_S of -5V to +600V. Logic state held for V_S of -5V to -V_{BS}.

■ THERMAL DATA

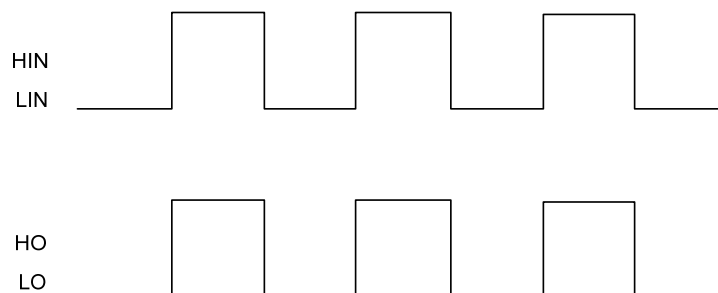
PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	200	°C/W

■ ELECTRICAL CHARACTERISTICS

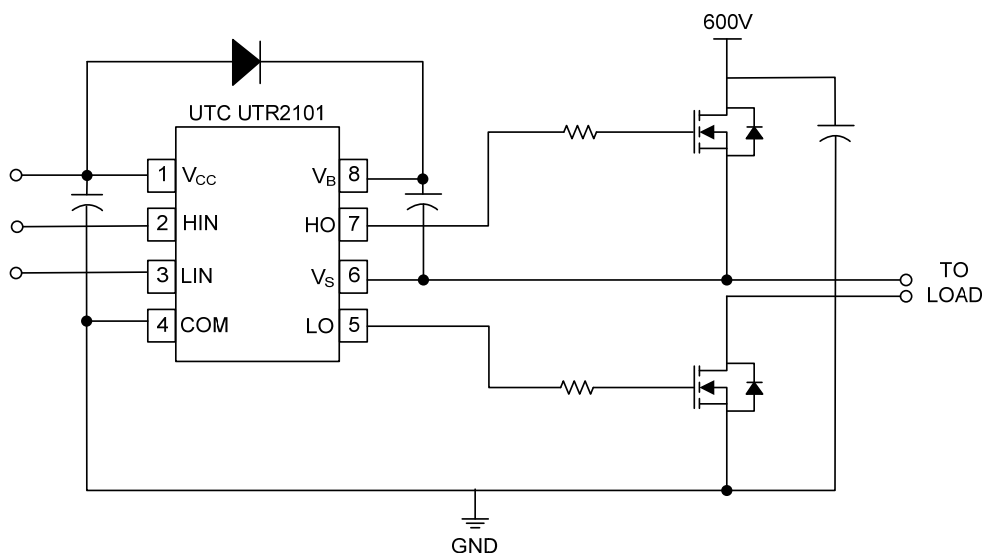
[V_{BIAS} (V_{CC} , V_{BS})=15V and $T_A=25^\circ\text{C}$ unless otherwise specified. The V_{IN} , V_{TH} , and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.]

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Turn-ON Propagation Delay	t_{on}	$V_S=0V$		200	300	ns
Turn-OFF Propagation Delay	t_{off}	$V_S=600V$		300	400	ns
Turn-ON Rise Time	t_r			70	170	ns
Turn-OFF Fall Time	t_f			35	90	ns
Delay matching, HS & LS Turn-ON/OFF	MT				90	ns
Logic "1" input voltage	V_{IH}	$V_{CC}=10V\sim 20V$	3.0			V
Logic "0" input voltage	V_{IL}				0.8	V
High level Output Voltage, $V_{BIAS} - V_O$	V_{OH}	$I_O=2mA$		0.02	0.2	V
Low Level Output Voltage, V_O	V_{OL}			0.02	0.1	V
Offset Supply Leakage Current	I_{LK}	$V_B=V_S=600V$			50	μA
Quiescent V_{BS} Supply Current	I_{QBS}	$V_{IN}=0V$ or $5V$		15	55	μA
Quiescent V_{CC} Supply Current	I_{QCC}			150	270	μA
Logic "1" Input Bias Current	I_{IN+}	$V_{IN}=5V$		3	10	μA
Logic "0" Input Bias Current	I_{IN-}	$V_{IN}=0V$			1	μA
V_{CC} Supply Undervoltage Positive Going Threshold	V_{CCUV+}		8	8.9	9.8	V
V_{CC} Supply Undervoltage Negative Going Threshold	V_{CCUV-}		7.4	8.2	9	V
Output High Short Circuit Pulsed Current	I_{O+}	$P_W \leq 10\mu s$, $V_O=0V$	130	290		mA
Output Low Short Circuit Pulsed Current	I_{O-}	$P_W \leq 10\mu s$, $V_O=15V$	200	360		mA

■ TIMING DIAGRAM



■ TYPICAL APPLICATION CIRCUIT



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